

MG032B420010A

3 phase Inverter Module

Feature

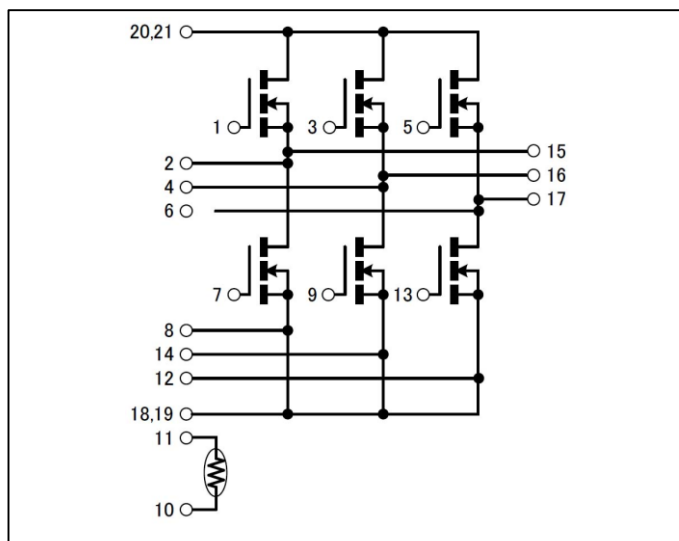
- 3 phase Inverter
- MOSFET(N-channel)
- High current capacity
- Isolated package
- Low Ron
- Pb free terminal
- RoHS:Yes

Outline

House Name: MG032



Equivalent circuit



Absolute maximum ratings (Tc = 25°C unless otherwise specified)

MOSFET

Item	Symbol	Conditions	Ratings	Unit
Channel temperature	T _{ch}		150	°C
Drain-source voltage	V _{DSS}		100	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current (DC)	I _D	Ratings per 2 chip	420	A
Continuous drain current (Peak)	I _{DP}	Pulse width 10μs, Duty = 1/100, Ratings per 1 arm	840	A
Total power dissipation	P _T	Ratings per 2 chip	500	W
Single avalanche current	I _{AS}	Starting T _{ch} =25°C, T _{ch} ≤150°C, Ratings per 2 chip	108	A
Single avalanche energy	E _{AS}	Starting T _{ch} =25°C, T _{ch} ≤150°C, Ratings per 2 chip	580	mJ

Module

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	T _{stg}		-40~125	°C
Dielectric strength	V _{dis}	Terminal to Cu base, AC50Hz 1 minute, Cutoff=5mA	2.0	kV
Mounting torque	TOR	Fixing screw M5 (for mount module)	3.5	N · m
		Fixing screw M6 (for external connection)	4.5	

Electrical and thermal characteristics (Tc=25°C unless otherwise specified.)

These are characteristics of the 2 chip unless otherwise specified.

MOSFET

Item	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D =2mA, V _{GS} =0V	100	—	—	V
Zero gate voltage drain current	I _{DSS}	V _{DS} =100V, V _{GS} =0V	—	—	4	μA
Gate-source leakage current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	—	—	±0.2	μA
Drain-source on-state resistance	R _{DS(ON)}	I _D =210A, V _{GS} =10V	—	0.99	1.37	mΩ
Gate threshold voltage	V _{TH}	I _D =2mA, V _{DS} =10V	2.0	3.0	4.0	V
Source-drain diode forward voltage	V _{SD}	I _S =210A, V _{GS} =0V	—	—	1.5	V
Total gate charge	Q _g	V _{DD} =80V, V _{GS} =10V, I _D =180A, Rating of per MOSFET	—	500	—	nC
Gate to source charge	Q _{gs}		—	130	—	
Gate to drain charge	Q _{gd}		—	210	—	
Input capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHz	—	91800	—	pF
Reverse transfer capacitance	C _{rss}		—	8260	—	
Output capacitance	C _{oss}		—	12290	—	

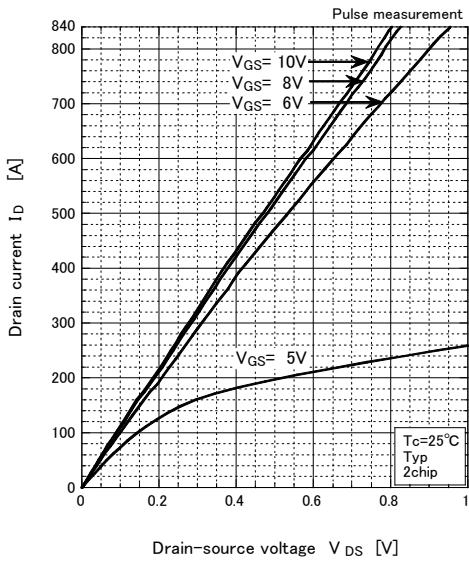
1SK-188202-1

Turn-on delay time	td(on)	I _D =90A , R _L =0.55Ω , V _{DD} =50V , R _G =0Ω , V _{GS(+)} =10V , V _{GS(-)} =0V , Rating of per MOSFET	—	20	—	ns
Rise time	tr		—	140	—	
Turn-off delay time	td(off)		—	473	—	
Fall time	tf		—	275	—	

Module

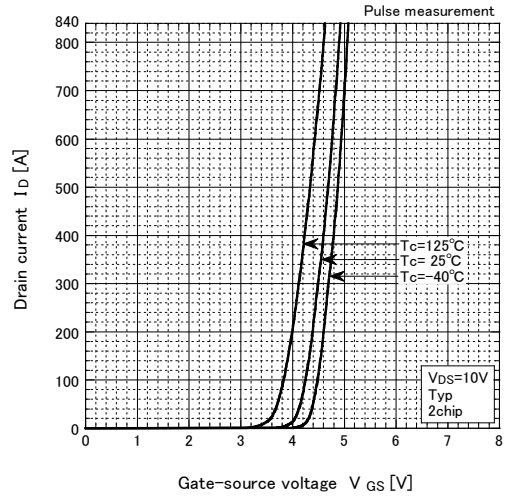
Item	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Thermal resistance	R _{th(j-c)}	Junction to case , With heatsink	—	—	0.25	°C/W

Typical output characteristics



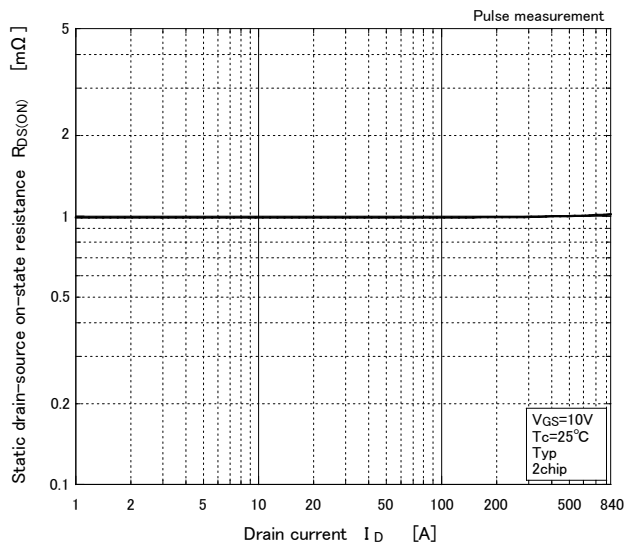
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Transfer characteristics



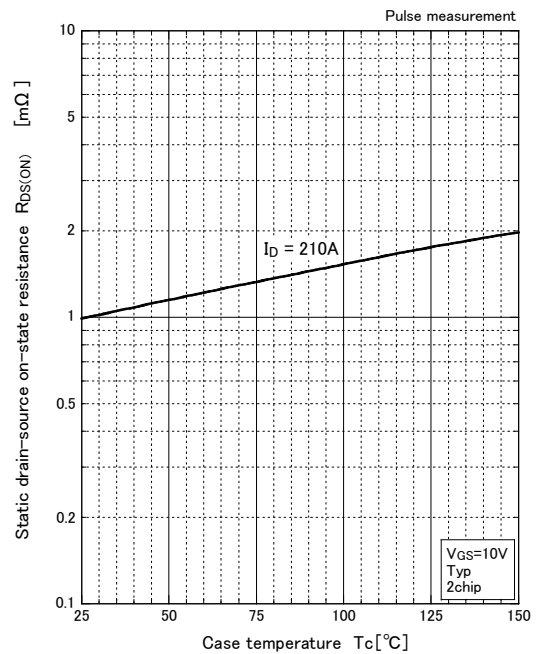
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Static drain-source on-state resistance vs drain current



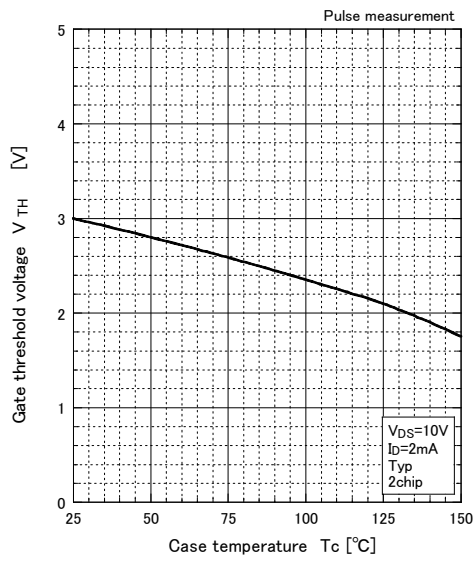
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Static drain-source on-state resistance vs case temperature



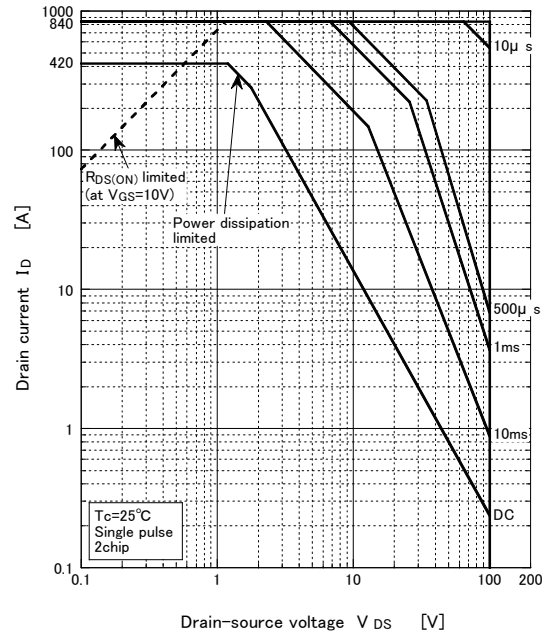
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Gate threshold voltage vs case temperature

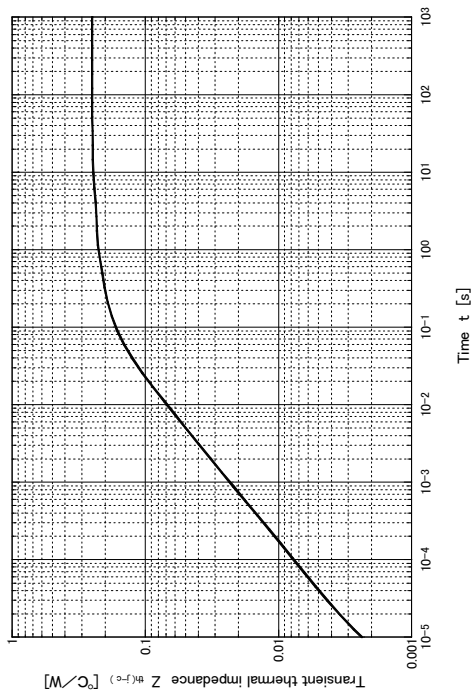


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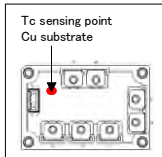
Safe operating area



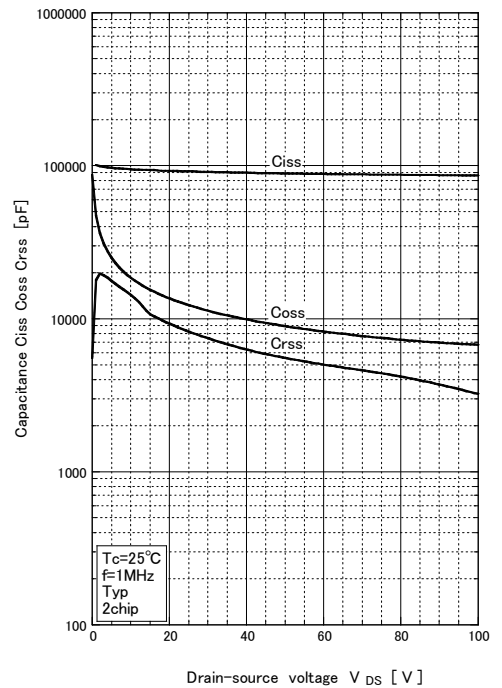
Transient thermal impedance



T_c sensing point

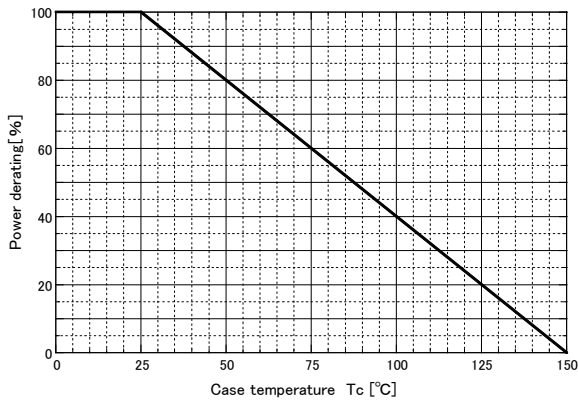


Capacitance characteristics

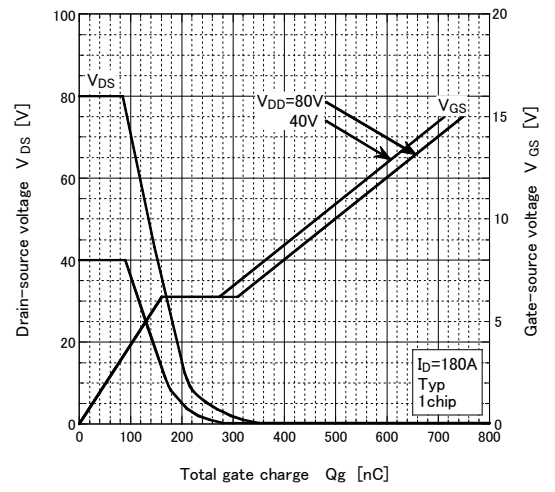


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Power derating - case temperature

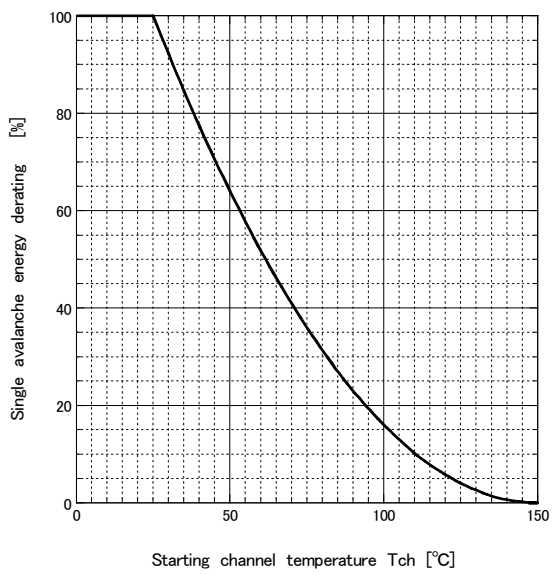


Gate charge characteristics



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Single avalanche energy derating vs channel temperature

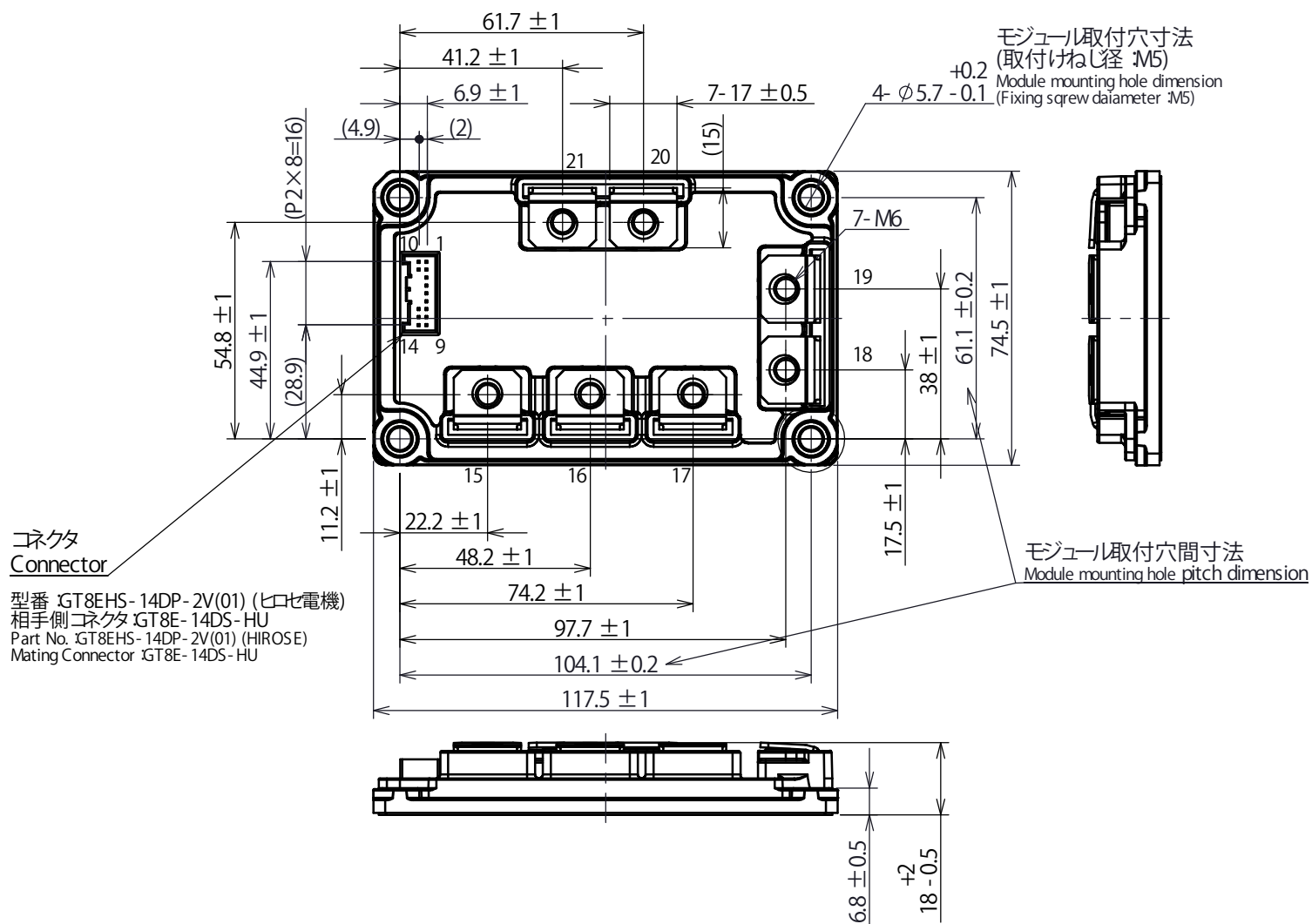


Package Outline-Dimensions

unit:mm

F6

JEDEC Code	-
JEITA Code	-
House Name	MG032



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